

### **Audio Jack Detector with Send / End Detect**

#### **DESCRIPTION**

The DG2592 is an audio jack detector and pop noise control switch IC. It integrates the circuits necessary to detect the presence of a stereo headset with a microphone and send / end control button.

When there is no ear phone detected, the DG2592 connects the microphone bias line to ground through the MIC pin. The DG2592 also gives a logic high signal to the baseband controller through the DET pin.

The DG2592 senses the DC levels at both L\_Detect and GND\_Detect. When an ear phone is plugged in, the voltage at both pins will go low. The DG2592 will indicate the presence of the ear phone by pulling DET low and the MIC switch will turn off.

The DG2592 is available in small miniQFN10 of 1.4 mm x 1.8 mm x 0.55 mm and ultra thin UTMQFN10 of 0.35 mm thickness.

### **FEATURES**

- Wide operating voltage range: 1.6 V to 5.5 V
- $\bullet$  Low quiescent current of 10  $\mu A,$  max. at  $V_{DD}=1.8\;V$
- Integrated sense comparator for audio L of  $1.4~V \pm 5~\%$  threshold



- 1.2 Ω/max. MIC bias switch provides quick discharge and clamping
- ESD Protected
  - Human body model > 8 kV
  - Charged device model > 2 kV
  - IEC 61000-4-2 air discharge > 15 kV
  - IEC 61000-4-2 contact discharge > 8 kV
- Ultra thin and compact miniQFN10 and UTDFN10
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **APPLICATIONS**

- Cellular phones
- Tablet devices
- Portable media players
- · Digital cameras

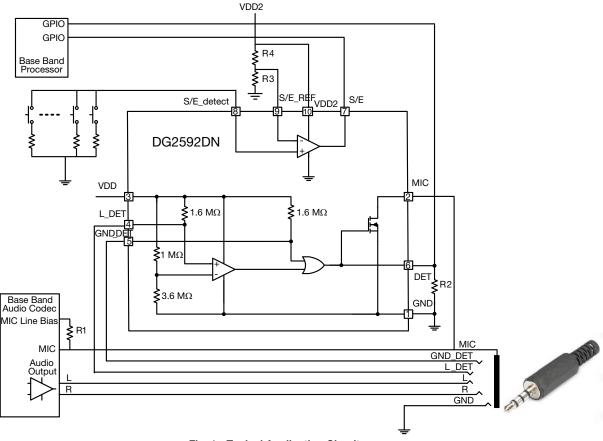


Fig. 1 - Typical Application Circuit

### **PACKAGE OUTLINE**

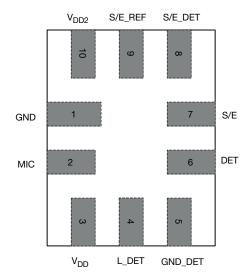
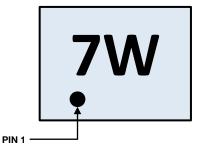


Fig. 2 - Device Pin Out miniQFN10 Top View, Pin 1 Dot Marking is on Top of the Device

PIN DESCRIPTION						
PIN#	NAME	TYPE	FUNCTION			
1	GND	Power	Ground			
2	MIC	Output	Microphone bias switch input			
3	V <sub>DD</sub>	Power	Power supply for ear jack plug in detection circuit. A bypass capacitor of 0.1 µF is recommended as close as possible to this pin			
4	L_DET	Input	Connected to L_DET pin at audio jack			
5	GND_DET	Input	Connect to GND_DET pin at audio jack			
6	DET	Output	Detect logic output connected to baseband controller			
7	S/E	Output	S/E detect comparator output			
8	S/E_DET	Input	Non-inverting input of S/E press detection comparator			
9	S/E_REF	Input	Inverting input of S/E press detection comparator. External voltage is provided as press detection reference threshold			
10	V <sub>DD2</sub>	Power	Power supply pin for the S/E detection circuit. A bypass capacitor of 0.1 $\mu$ F is recommended as close as possible to this pin			

ORDERING INFORMATION							
PART NUMBER	FUNCTION	TEMPERATURE RANGE	PACKAGE	SIZE	REEL QUANTITY		
DG2592DN-T1-GE4	Audio jack detector	-40 °C to 85 °C	miniQFN-10	1.4 mm x 1.8 mm x 0.55 mm	3000		
DG2592DN1-T1-GE4	with S/E detect	-40 0 10 85 0	UTMQFN-10 1.4 mm x 1.8 mm x		3000		

### **DEVICE MARKING**



7 = DG2592 Marking Code, W = Date / Lot Traceability Code



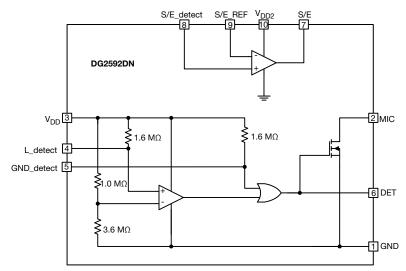


Fig. 3 - Functional Block Diagram

TRUTH TABLE						
INPUTS		OUT	ALIDIO LACK			
L_DET	GND_DET	DET	MIC	AUDIO JACK		
0	0	Low	High	Detected		
1	0	High	Low	Not detected		
0	1	High	Low	Not detected		
1	1	High	Low	Not detected		

<b>ABSOLUTE MAXIMUM RA</b>	TINGS			
PINS OR PARAMETERS	CONDITIONS	LIMITS	UNIT	
$V_{DD}, V_{DD2}$	Reference to GND		-0.3 to 6	
L_Detect, GND_Detect, DET	Reference to GND		-0.3 V to V <sub>DD</sub>	.,
S/E_DET, S/E_REF, S/E	Reference to GND		-0.3 V to V <sub>DD2</sub>	V
MIC			-0.3 to 6	
Storage Temperature			-65 to +150	°C
MSL	Moisture sensitivity level (JEDEC® J-STD-020)		1	Level
I <sub>MIC</sub>	Switch DC current		200	
I <sub>MICPEAK</sub>	Switch peak current (pulsed at 1 ms, < 10 % du	uty cycle)	500	mA
Latch Up Current	JESD78	± 600		
	Human body model; ANSI / ESDA / JEDEC JS-	> 8000		
	Charged device model; JESD22-C101	> 2000		
ESD	Machine model; JESD22-A115	> 400	V	
	IEC61000-2-4, level 4	Contact	> 8000	
	L_DET, GND_DET, MIC and GND pins	Air	> 15 000	
RECOMMENDED OPERATING CON	DITION			
$V_{DD}, V_{DD2}$			1.6 to 5.5	V
Ear Jack Detection Input Pins			0 to V <sub>DD</sub>	V
S/E Press Detection Input Pins	0 to V <sub>DD2</sub>	V		
MIC Bias Voltage	0 to 5.5	V		
Operating Junction Temperature	-40 to +125	°C		

#### Note

• The control logic pins should not float and should be set to either high or low logic levels.

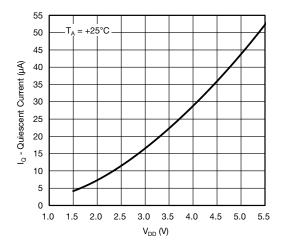
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



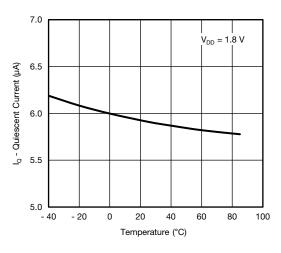
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ELECTRICAL CHARACTERISTICS							
		TEST CONDITION		LIMITS			
PARAMETER	SYMBOL	UNLESS OTHERWISE SPECIFIED, $V_{DD} = 1.8 \ V, V_{DD2} = 2.1 \ V, T_A = -40 \ ^{\circ}\text{C} \ \text{to} \ 85 \ ^{\circ}\text{C},$ TYPICAL VALUES are at 25 $\ ^{\circ}\text{C}$	MIN.	TYP.	MAX.	UNIT	
Quiescent Current	ΙQ	L_Detect, GND_Detect are open	-	6	10		
Ear Jack In Current	I <sub>DD</sub>	L_Detect, GND_Detect are connected with 10 k $\Omega$ to GND	-	3	6	μΑ	
S/E Detection Current	I <sub>DD2</sub>	S/E_DET =0 V, S/E_REF = 1.05 V	-	2	3.5		
L_Detect Reference Voltage	$V_{TH\_L}$	L_DET switching low to high	1.33	1.4	1.5	V	
Propagation Delay to DET	t <sub>PLH</sub>	C <sub>OUT</sub> = 15 pF, GND_DET = 0 V, L_DET = 1.52 V to DET = 0.9 V	80	149	300	no	
Propagation Delay to DET	t <sub>PHL</sub>	C <sub>OUT</sub> = 15 pF, GND_DET = 0 V, L_DET = 1.31 V to DET = 0.9 V	130	325	550	ns	
Low Voltage L_DET Leakage	IL <sub>L_DET</sub>	L_DET = 0 V	-	0.84	2	μΑ	
High Voltage L_DET Leakage	IH <sub>L_DET</sub>	L_DET = 1.8 V	-	30	-	рА	
L_DET Input Capacitance	C <sub>L_DET</sub>		-	4	-	pF	
GND_Detect Logic Low Voltage	$V_{IL\_GND}$		0.63	0.86	-	V	
GND_Detect Logic High Voltage	$V_{IH\_GND}$		-	0.89	1.17	V	
GND_DET Propagation Delay to DET	t <sub>PGND_DET</sub>	$C_{OUT}$ = 15 pF, $R_L$ = 1 M $\Omega$ , L_DET = 0 V, GND_DET switches between 0 V and 1.8 V		10	-	ns	
Low Voltage GND_DET Leakage	I <sub>IL</sub>	GND_DET = 0 V		0.93	2	μА	
High Voltage GND_DET Leakage	I <sub>IH</sub>	GND_DET = 1.8 V		80	-	рА	
GND_DET Input Capacitance	C <sub>G_DET</sub>	f = 1 MHz	-	3.5	-	pF	
MIC Pull Down Resistance	R <sub>MIC</sub>	I <sub>MIC</sub> = 1 mA L_Detect, GND_Detect = open	-	-	1.25	Ω	
MIC Leakage		V <sub>MIC</sub> = 2.4 V		-	1	μΑ	
DET Pull Up Resistance	R <sub>OUT</sub> H	L_Detect, GND_Detect = open	-	135	200	Ω	
DET Pull Down Resistance	R <sub>OUT</sub> L	L_Detect, GND_Detect are connected with 10 k $\Omega$ to GND	-	120	200		
DET High Logic Voltage	V <sub>OUT</sub> H	I <sub>DET</sub> = 0.1 mA, L_Detect, GND_Detect = open	1.6	-	-		
DET Low Logic Voltage	V <sub>OUT</sub> L	$I_{DET}$ = 0.1 mA, L_Detect, GND_Detect are connected with 10 k $\Omega$ to GND	-	-	0.3	V	
DET Rise Time	t <sub>DET_R</sub>	$C_{OUT}$ = 15 pF, $R_L$ = 1 M $\Omega$ , DET = 10 % to 90 %	-	14	-		
DET Fall Time	t <sub>DET_F</sub>	$C_{OUT}$ = 15 pF, $R_L$ = 1 M $\Omega$ , DET = 90 % to 10 %	-	4.4	-	ns	
Propagation Delay to S/E	t <sub>PS/E</sub>	$C_{OUT}$ = 15 pF, $R_L$ = 1 M $\Omega$ , $V_{CM}$ = mid-supply, 100 mV overdrive		170	500		
Input Leakage	I <sub>SE_IN</sub>	V <sub>CM</sub> = 0.9 V	-	4	-	рА	
Input Capacitance	C <sub>SE_IN</sub>	f = 1 MHz	-	3.5	-	pF	
Voltage Output Low	V <sub>OL</sub>	I <sub>OL</sub> = 0.1 mA	-	-	0.2	.,	
Voltage Output High	V <sub>OH</sub>	I <sub>OH</sub> = 0.1 mA	1.9	-	-	V	
Rise Time	t <sub>S/E_R</sub>	$C_{OUT}$ = 15 pF, $R_L$ = 1 M $\Omega$ , S/E = 10 % to 90 %	-	16	-		
Fall Time	t <sub>S/E_F</sub>	$C_{OUT}$ = 15 pF, $R_L$ = 1 M $\Omega$ , S/E = 90 % to 10 %	-	12.1	-	ns	

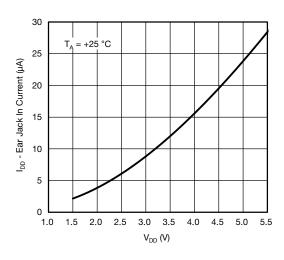




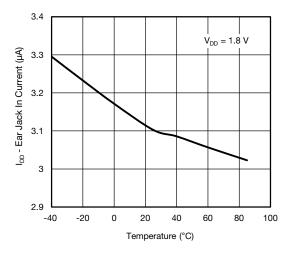
#### Quiescent Current vs. V<sub>DD</sub>



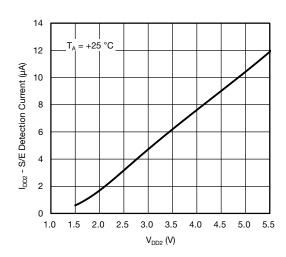
**Quiescent Current vs. Temperature** 



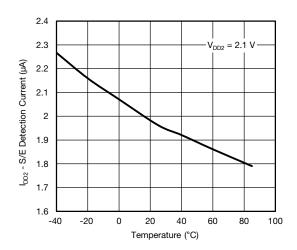
Ear Jack In Current vs. V<sub>DD</sub>



Ear Jack In Current vs. Temperature

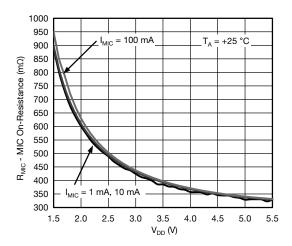


S/E Detection Current vs. V<sub>DD2</sub>

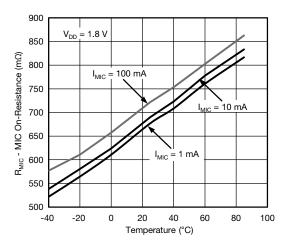


S/E Detection Current vs. Temperature

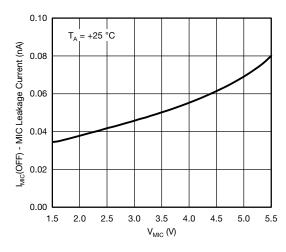




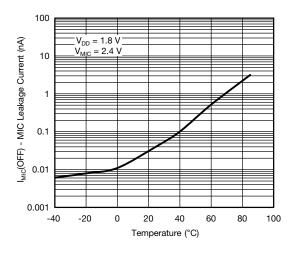
MIC On Resistance vs. V<sub>DD</sub>



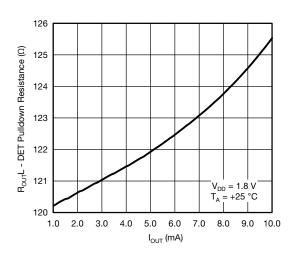
MIC On Resistance vs. Temperature



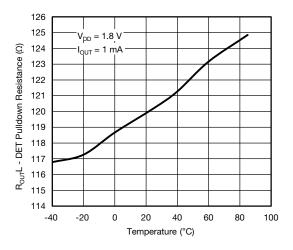
MIC Leakage Current vs. V<sub>MIC</sub>



MIC Leakage Current vs. Temperature

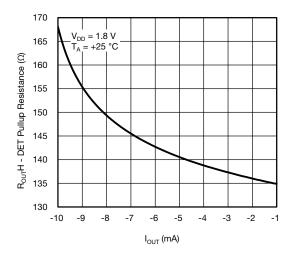


DET Pulldown Resistance vs. I<sub>OUT</sub>

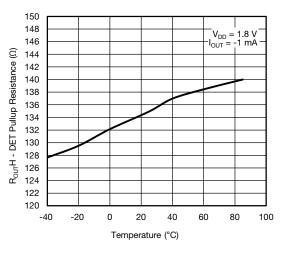


**DET Pulldown Resistance vs. Temperature** 

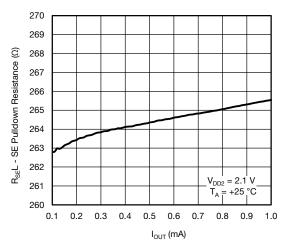




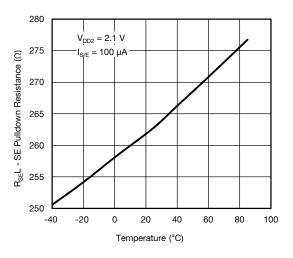
DET Pullup Resistance vs. IOUT



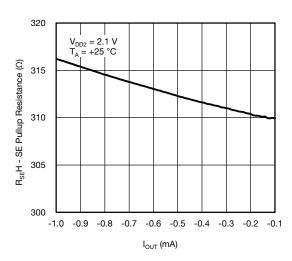
**DET Pullup Resistance vs. Temperature** 



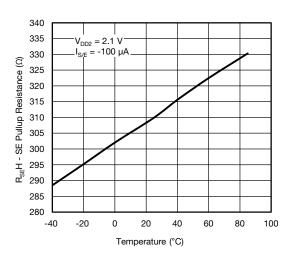
SE Puldown Resistance vs. IOUT



SE Pulldown Resistance vs. Temperature

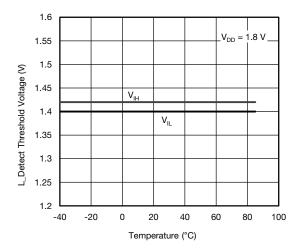


SE Pullup Resistance vs. IOUT

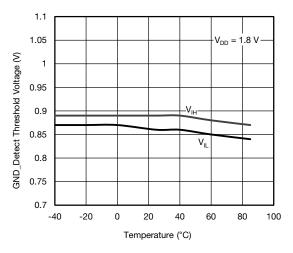


SE Pullup Resistance vs. Temperature

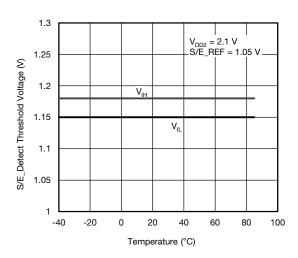




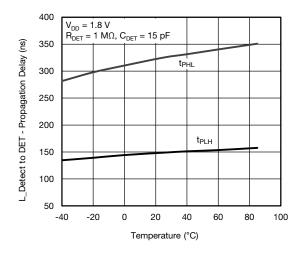
L\_Detect Threshold Voltage vs. Temperature



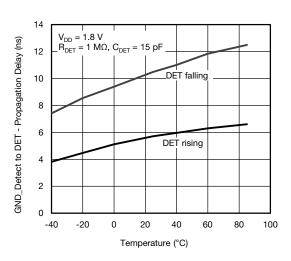
**GND\_Detect Threshold Voltage vs. Temperature** 



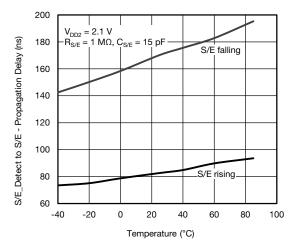
S/E\_Detect Threshold Voltage vs. Temperature



L\_Detect to DET Propagation Delay vs. Temperature

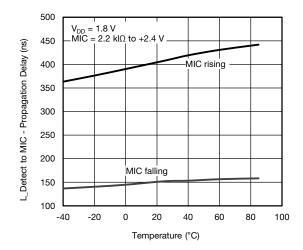


GND\_Detect to DET Propagation Delay vs. Temperature

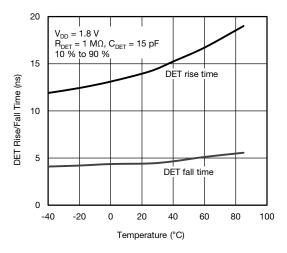


S/E\_Detect to S/E Propagation Delay vs. Temperature

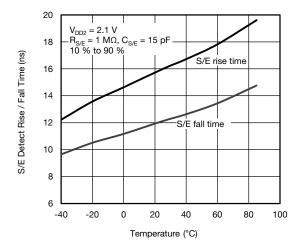




#### L\_Detect to MIC Propagation Delay vs. Temperature



### **DET Rise / Fall Time vs. Temperature**



S/E\_Detect to Rise / Fall Time vs. Temperature

### **TEST CIRCUIT**

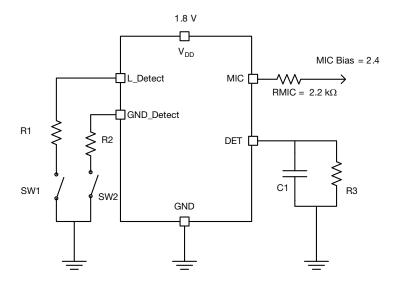


Fig. 4 - Test Circuit

#### **TIMING DIAGRAM**

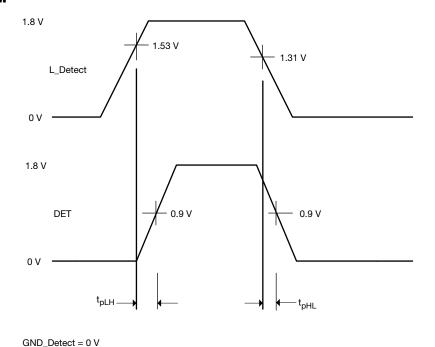
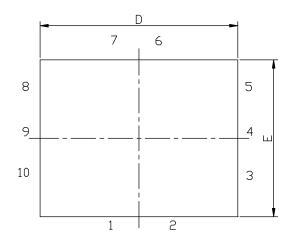


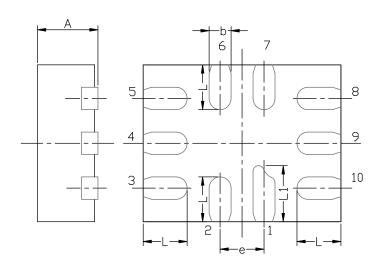
Fig. 5 - Timing Diagram

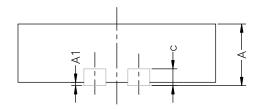
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# MINI QFN-10L CASE OUTLINE







DIM	MILLIMETERS			INCHES			
	MIN.	NAM.	MAX.	MIN.	NAM.	MAX.	
А	0.45	0.55	0.60	0.0177	0.0217	0.0236	
A1	0.00	-	0.05	0.000	-	0.002	
b	0.15	0.20	0.25	0.006	0.008	0.010	
С		0.150 or 0.127 REF <sup>(1)</sup>			0.006 or 0.005 REF <sup>(1)</sup>		
D	1.70	1.80	1.90	0.067	0.071	0.075	
E	1.30	1.40	1.50	0.051	0.055	0.059	
е	0.40 BSC				0.016 BSC		
L	0.35	0.40	0.45	0.014	0.016	0.018	
L1	0.45	0.50	0.55	0.0177	0.0197	0.0217	

#### Note

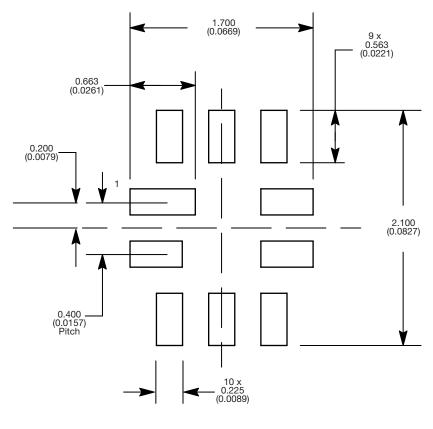
 $^{(1)}$  The dimension depends on the leadframe that assembly house used.

ECN T16-0163-Rev. B, 16-May-16 DWG: 5957



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### **RECOMMENDED MINIMUM PADS FOR MINI QFN 10L**



Mounting Footprint Dimensions in mm (inch)



## **Legal Disclaimer Notice**

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Revision: 02-Oct-12 Document Number: 91000